

# GP1A53HRJ00F

# Gap: 5mm, Slit: 0.5mm \*OPIC Output Case package Transmissive Photointerrupter



#### **■** Description

**GP1A53HRJ00F** is a standard, OPIC output, transmissive photointerrupter with opposing emitter and detector in a case, providing non-contact sensing. For this family of devices, the emitter and detector are inserted in a case, resulting in a through-hole design.

#### **■**Features

- 1. Transmissive with OPIC output
- 2. Highlights:
  - · Vertical Slit for alternate motion detection
  - Output Low Level at intercepting optical path
- 3. Key Parameters:
  - Gap Width: 5mm
  - · Slit Width (detector side): 0.5mm
  - Package: 13.7×10×5.2mm
- 4. Lead free and RoHS directive compliant

# ■ Agency approvals/Compliance

1. Compliant with RoHS directive

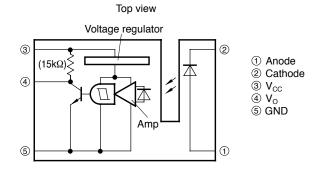
# **■**Applications

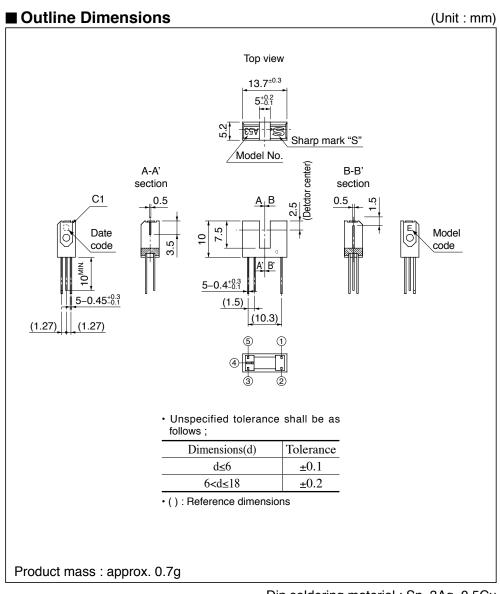
- General purpose detection of object presence or motion.
- 2. Example: Printer, FAX, Optical storage unit

<sup>\* &</sup>quot;OPIC"(Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and a signalprocessing



# ■ Internal Connection Diagram





Dip soldering material: Sn-3Ag-0.5Cu



Date code			
Month of production			
Month	Mark		
1	1		
2	2		
3	3		
4	4		
5	5		
6	6		
7	7		
8	8		
9	9		
10	X		
11	Y		
12	7.		

Model code	Year of production
Wiodel Code	(Christian year)
Е	Even year
e	Odd year

# Country of origin

Japan, Indonesia or Philippines (Indicated on the packing case)



■ Absolute Maximum Ratings (T <sub>a</sub> =25°C				$(T_a=25^{\circ}C)$
	Parameter	Symbol	Rating	Unit
*1 Forward current		$I_{F}$	50	mA
Innut	*1, <sup>2</sup> Peak forward current	$I_{FM}$	1	A
Iliput	Input Reverse voltage		6	V
	Power dissipation	P	75	mW
	Supply voltage	$V_{CC}$	-0.5 to +17	V
Output	Output current	Io	50	mA
	Power dissipation	Po	250	mW
Operating temperature		Topr	-25 to +85	°C
Storage temperature		$T_{stg}$	-40 to +100	°C
*3Soldering temperature		$T_{sol}$	260	°C

<sup>\*1</sup> The derating factors of absolute maximum ratings due to ambient temperature are shown in Fig. 1, 2, 3 \*2 Pulse width  $\leq$  100 $\mu$ s, Duty ratio=0.01

# **■** Electro-optical Characteristics

 $(T_a=25^{\circ}C)$ 

		Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Lamut		Forward voltage	$V_{F}$	I <sub>F</sub> =8mA	_	1.14	1.4	V
Input		Reverse current	$I_R$	$V_R=3V$	_	_	10	μΑ
		Operating supply voltage	$V_{CC}$	_	4.5	_	17	V
		Low level output voltage	$V_{OL}$	$V_{CC}=5V, I_{OL}=16mA, I_{F}=0$	_	0.15	0.4	V
Output		High level output voltage	$V_{OH}$	$V_{CC}$ =5V, $I_F$ =8mA	4.9	_	_	V
Low level supply current	Low level supply current	$I_{CCL}$	$V_{CC}=5V$ , $I_F=0$	_	1.7	3.8	mA	
		High level supply current	$I_{\text{CCH}}$	$V_{CC}=5V$ , $I_F=8mA$	_	0.7	2.2	mA
	*4	"Low→High" threshold input current	$I_{FLH}$	$V_{CC}=5V$	_	1.5	8	mA
Transfer	*5	Hysteresis	$I_{FHL}/I_{FLH}$	$V_{CC}=5V$	0.55	0.75	0.95	_
	*6	"Low→High" Propagation delay time	$t_{PLH}$	$V_{CC}$ =5V, $I_F$ =8mA, $R_L$ =280 $\Omega$	_	3	9	
teristics	charac-	"High→Low" Propagation delay time	$t_{\mathrm{PHL}}$		_	5	15	
teristics	Responce	Rise time	t <sub>r</sub>		_	0.1	0.5	μs
	Res	Fall time	$t_{\rm f}$		_	0.05	0.5	

 $<sup>^{\</sup>circ}4$   $I_{\rm FLH}$  represents forward current when output goes from "Low" to "High".  $^{\circ}5$   $I_{\rm FHL}$  represents forward current when output goes from "High" to "Low".  $^{\circ}6$  Test circuit for response time is shown in Fig.12.

<sup>\*3</sup> For 5s or less



Fig.1 Forward Current vs.

Ambient Temperature

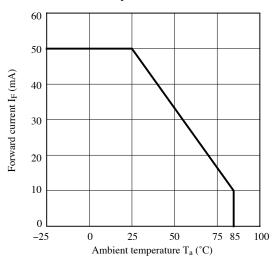


Fig.3 Low Level Output Current vs.
Ambient Temperature

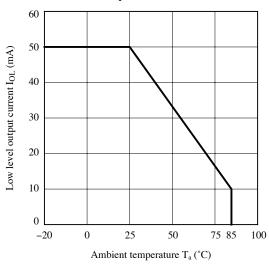


Fig.5 Relative Threshold Input Current vs. Supply Voltage

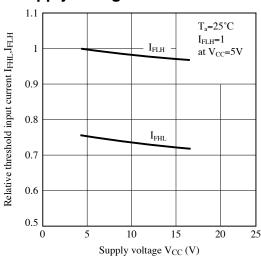


Fig.2 Output Power Dissipation vs. Ambient Temperature

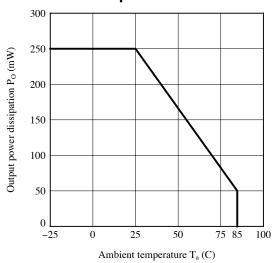


Fig.4 Forward Current vs. Forward Voltage

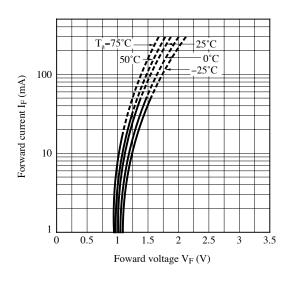


Fig.6 Relative Threshold Input Current vs. Ambient Temperature

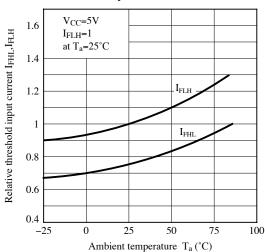




Fig.7 Low Level Output Voltage vs. Low Level Output Current

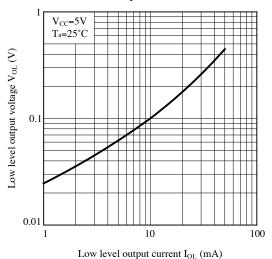


Fig.9 Supply Current vs.

Ambient Temperature

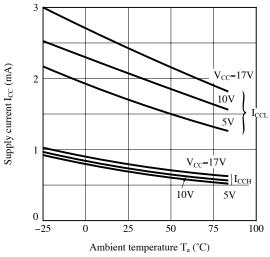


Fig.11 Rise Time,Fall Time vs. Load Resistance

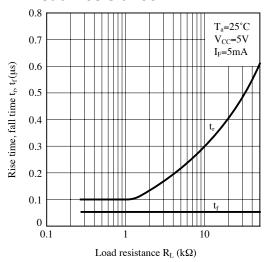


Fig.8 Low Level Output Voltage vs. Ambient Temperature

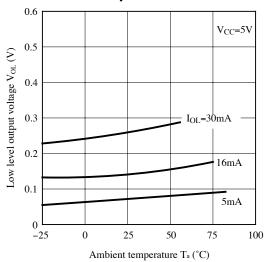


Fig.10 Propagation Delay Time vs. Forward Current

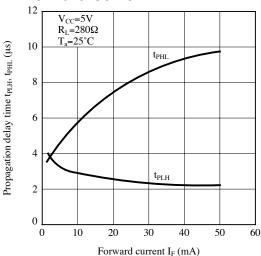
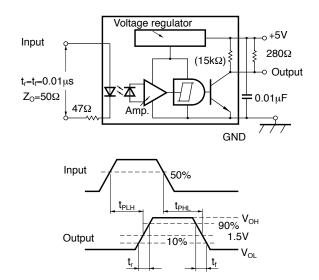


Fig.12 Test Circuit for Response Time



Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



#### **■** Design Considerations

#### Recommended operating conditions

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Output current	Io	_	_	16	mA
Forward current	$I_{\mathrm{F}}$	10	_	20	mA
Operating terperature	Topr	0	_	70	°C

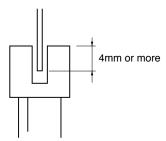
#### Notes about static electricity

Transisiter of detector side in bipolar configuration may be damaged by static electricity due to its minute design.

When handing these devices, general countermeasure against static electricity should be taken to avoid breakdown of devices or degradation of characteristics.

# Design guide

- 1) Prevention of detection error
  - To prevent photointerrupter from faulty operation caused by external light, do not set the detecting face to the external light.
- 2) In order to stabilize power supply line, connect a by-pass capacitor of more than  $0.01\mu F$  between  $V_{CC}$  and GND near the device.
- 3) Position of opaque board
  - Opaque board shall be installed at place 4mm or more from the top of elements. (Example)



This product is not designed against irradiation and incorporates non-coherent IRED.

#### Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.



#### Parts

This product is assembled using the below parts.

• Photodetector (qty. : 1) [Using a silicon photodiode as light detecting portion, and a bipolar IC as signal processing circuit]

Category	Maximum Sensitivity wavelength (nm)	Sensitivity wavelength (nm)	Response time (µs)
Photodiode	900	400 to 1 200	3

# • Photo emitter (qty.: 1)

Category	Material	Maximum light emitting wavelength (nm)	I/O Frequency (MHz)
Infrared emitting diode (non-coherent)	Gallium arsenide (GaAs)	950	0.3

# Material

Case	Lead frame plating
Black NORYL resin	Solder dip. (Sn-3Ag-0.5Cu)

#### Others

Laser generator is not used.



#### ■ Manufacturing Guidelines

#### Soldering Method

#### Flow Soldering:

Soldering should be completed below 260°C and within 5 s.

Please take care not to let any external force exert on lead pins.

Please don't do soldering with preheating, and please don't do soldering by reflow.

#### Hand soldering

Hand soldering should be completed within 3 s when the point of solder iron is below 350°C.

Please solder within one time.

Please don't touch the terminals directly by soldering iron.

Soldered product shall treat at normal temperature.

#### Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the cooling and soldering conditions.

#### Flux

Some flux, which is used in soldering, may crack the package due to synergistic effect of alcohol in flux and the rise in temperature by heat in soldering. Therefore, in using flux, please make sure that it does not have any influence on appearance and reliability of the photointerrupter.



#### Cleaning instructions

#### Solvent cleaning:

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

#### Ultrasonic cleaning:

The effect to device by ultrasonic cleaning differs by cleaning bath size, ultrasonic power output, cleaning time, PCB size or device mounting condition etc.

Please test it in actual using condition and confirm that doesn't occur any defect before starting the ultrasonic cleaning.

#### Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.

#### Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



# ■ Package specification

#### Case package

#### Package materials

Anti-static plastic bag: Polyethtylene

Moltopren: Urethane

Partition : Corrugated fiberboard
Packing case : Corrugated fiberboard

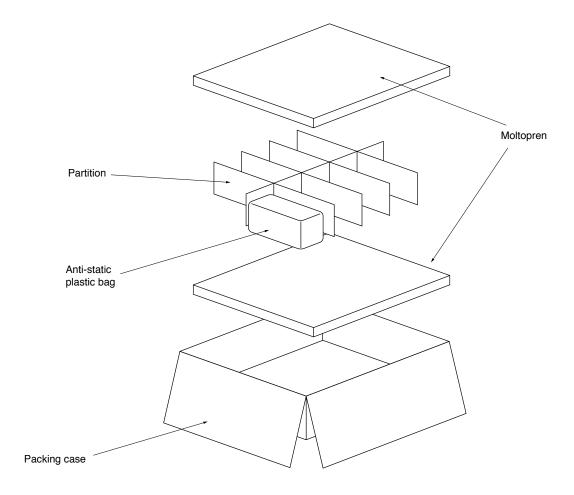
#### Package method

100 pcs of products shall be packaged in a plastic bag, Ends shall be fixed by stoppers. The bottom of the packing case is covered with moltopren, and the partition is set in the packing case. Each partition should have 1 plastic bag.

The 10 plastic bags containing a product are put in the packing case.

Moltopren should be located after all product are settled (1 packing contains 1 000 pcs).

#### Packing composition





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- --- Various safety devices, etc.
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